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Hyperfast Rectifier, 75 A FRED Pt[®] G5



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS							
I _{F(AV)}	75 A						
V _R	600 V						
V _F at I _F at 125 °C	1.2 V						
t _{rr} (typ.)	32						
I _{FSM}	650						
T _J max.	175 °C						
Package	TO-247AD 3L						
Circuit configuration	Single						

FEATURES

- Hyperfast and optimized Q_{rr}
- · Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV battery charging stations and high frequency stages of UPS applications.

MECHANICAL DATA

Case: TO-247AD 3L Molding compound meets UL 94 V-0 flammability rating Terminal: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Repetitive peak reverse voltage	V _{RRM}		600	V				
Average rectified forward current	I _{F(AV)}	T _C = 113 °C, D = 0.50	75					
Non-repetitive peak surge current	I _{FSM}	$T_{C} = 25$ °C, $t_{p} = 10$ ms, sine wave both anodes, (1) and (3) connected	650	А				
Repetitive peak forward current	I _{FRM}	T _C = 113 °C, D = 0.50, f = 20 kHz	150					
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C				

ELECTRICAL SPECIFICATIONS (T_J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS				
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	600	-	-				
Forward voltage	V _F	I _F = 75 A	-	1.3	1.7	V			
Forward voltage		I _F = 75 A, T _J = 125 °C	-	1.2	-				
Povoroo lookago ourrent	I _R	$V_{R} = V_{R}$ rated	-	-	25				
Reverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA			
Junction capacitance	CT	V _R = 200 V	-	96	-	pF			
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH			

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DYNAMIC RECOVERY CHARACTERISTICS (T_J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS			
		I _F = 1.0 A, dI _F /dt =	100 A/ μ s, V _R = 30 V	-	32	-			
Reverse recovery time	t _{rr}	T _J = 25 °C		-	52	-	ns		
		T _J = 125 °C		-	82	-			
Peak recovery current	$I_{\text{RRM}} = \frac{T_{\text{J}} = 25 \text{ °C}}{T_{\text{J}} = 125 \text{ °C}}$	T _J = 25 °C	I _F = 50 A dI _F /dt = 1000 A/μs V _R = 400 V	-	24	-	A		
Feat recovery current		T _J = 125 °C		-	51	-			
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	805	-	nC		
neverse recovery charge	Qrr	T _J = 125 °C		-	2515	-			
Reverse recovery time	+	T _J = 25 °C		-	57	-	ns		
neverse recovery time	t _{rr}	T _J = 125 °C		-	90	-	115		
Peak recovery current		T _J = 25 °C	I _F = 75 A dI _F /dt = 1000 A/μs V _B = 400 V	-	28	-	А		
Feak recovery current	I _{RRM}	T _J = 125 °C		-	58	-	~		
Deverse weeksterne	Q _{rr}	T _J = 25 °C		-	969	-	nC		
Reverse recovery charge	Qrr	T _J = 125 °C		-	3090	-	no		

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Thermal resistance, junction-to-case	R _{thJC}		-	-	0.5	°C/W			
Weight			-	5.5	-	g			
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)			
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C			
Marking device		Case style TO-247AD 3L	A5PH7506L						

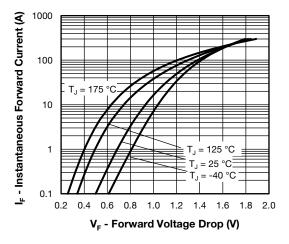


Fig. 1 - Forward Voltage Drop Characteristics

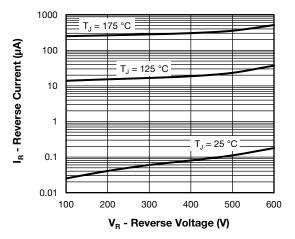


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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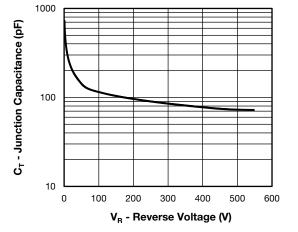


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

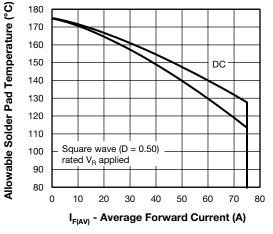


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

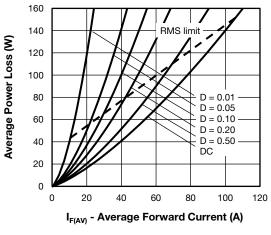


Fig. 5 - Forward Power Loss Characteristics

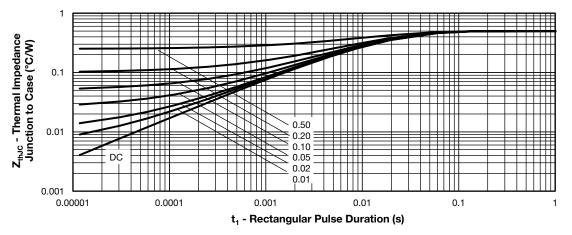


Fig. 6 - Transient Thermal Impedance, Junction to Case

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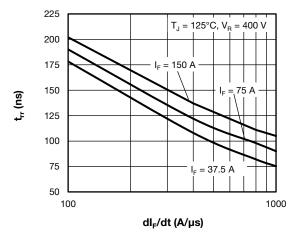


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

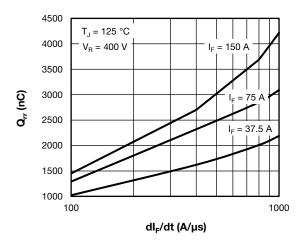


Fig. 8 - Typical Reverse Recovery Charge vs. dl_F/dt

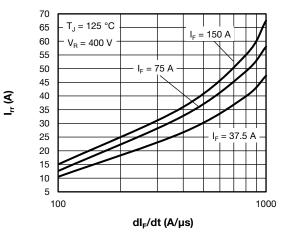


Fig. 9 - Typical Reverse Recovery Current vs. dl_F/dt

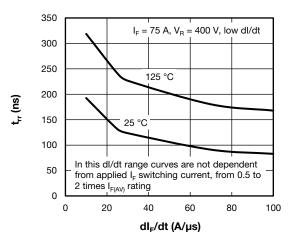
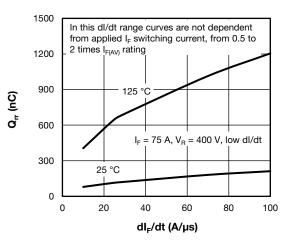


Fig. 10 - Typical Reverse Recovery Time vs. dI_F/dt





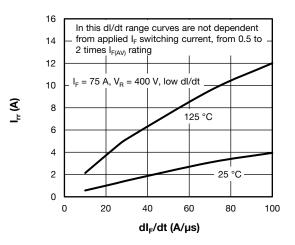


Fig. 12 - Typical Reverse Recovery Current vs. dl_F/dt

VS-A5PH7506L-N3

Revision: 28-Aug-2023

4

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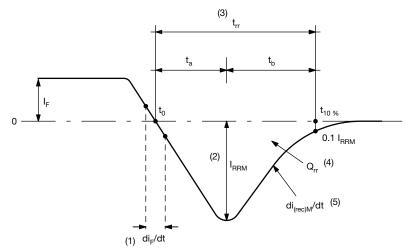


Fig. 13 - Reverse Recovery Waveform and Definitions

Notes

- $^{(1)}$ di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current (3) t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F , to point $t_{10\%}$, 0.1 I_{RRM} (4)

$$\mathsf{Q}_{\mathsf{rr}}$$
 - area under curve defined by t_0 and t_{10} %

$$Q_{rr} = \int_{t}^{t_{10\%}} I(t) dt$$

to $^{(5)}~di_{(rec)}M/dt$ - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE

Device code	VS-	Α	5	Р	н	75	06	L	-N3
	1	2	3	4	5	6	7	8	9
	1-Vishay Semiconductors product2-A = single diode, 2 anodes								
	 3 - 5 = Fred generation 5 4 - Package: P = TO-247 package 								
	5 - 6 -	Cur	rent rati	nst recov ng (75 =	= 75 A)				
	7 - 8 -	Pac	kage: L	ng (06 = = long l	ead (TC))		
	9 -			ntal digit gen-free		-complia	ant, and	totally I	ead (Pb

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-A5PH7506L-N3	25	500	Antistatic plastic tube						
LINKS TO RELATED DOCU	MENTS								
Dimensions		www.vishay.co	om/doc?95626						
Part marking information		www.vishay.co	om/doc?95007						
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TO-247AD 3L

DIMENSIONS in millimeters and inches



View B

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
с	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

(2, 52, 51) (4) Section C - C, D - D, E - E

SYMBOL	MILLIN	IETERS	INC	INCHES	
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	5 BSC	
ØК	0.254		0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØР	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51	BSC	0.217	' BSC	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

- ⁽³⁾ Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- ⁽⁵⁾ Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- ⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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1